# imall

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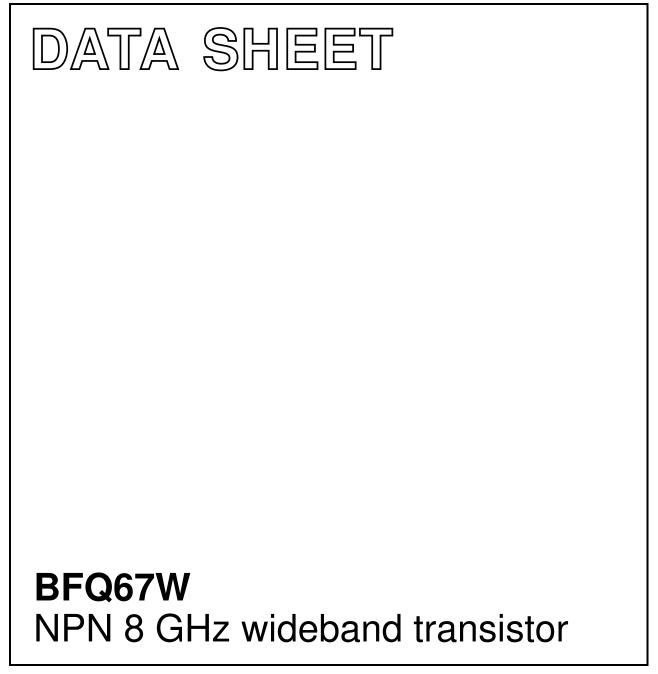


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DISCRETE SEMICONDUCTORS



Product specification

September 1995



PINNING

PIN

1

2

3

DESCRIPTION

Code: V2

base

emitter

collector

#### **FEATURES**

#### • High power gain

- Low noise figure
- · High transition frequency · Gold metallization ensures
- excellent reliability
- SOT323 envelope.

#### DESCRIPTION

NPN transistor in a plastic SOT323 envelope.

It is designed for wideband applications such as satellite TV tuners and RF portable communications equipment up to 2 GHz.

#### QUICK REFERENCE DATA

| SYMBOL           | PARAMETER                     | CONDITIONS   | MIN. | TYP. | MAX. | UNIT |
|------------------|-------------------------------|--|------|------|------|------|
| V <sub>CBO</sub> | collector-base voltage        | open emitter   | _    | -    | 20   | V    |
| V <sub>CEO</sub> | collector-emitter voltage     | open base  | -    | _    | 10   | V    |
| I <sub>C</sub>   | DC collector current          |  | -    | -    | 50   | mA   |
| P <sub>tot</sub> | total power dissipation       | up to $T_s = 118 \text{ °C}$ ; note 1  | -    | -    | 300  | mW   |
| h <sub>FE</sub>  | DC current gain               | $I_{C} = 15 \text{ mA}; V_{CE} = 5 \text{ V}; T_{j} = 25 \text{ °C}$                           | 60   | 100  | -    |      |
| f <sub>T</sub>   | transition frequency          | $I_{C} = 15 \text{ mA}; V_{CE} = 8 \text{ V}; f = 2 \text{ GHz};$<br>$T_{amb} = 25 \text{ °C}$ | -    | 8    | -    | GHz  |
| G <sub>UM</sub>  | maximum unilateral power gain | $I_c = 15 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$      | -    | 13   | -    | dB   |
| F                | noise figure                  | $I_c = 5 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz}$                                  | -    | 1.3  | _    | dB   |

#### LIMITING VALUES

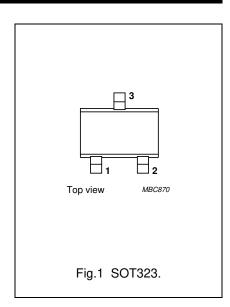
In accordance with the Absolute Maximum System (IEC 134).

| SYMBOL           | PARAMETER                 | CONDITIONS                            | MIN. | MAX. | UNIT |
|------------------|---------------------------|---------------------------------------|------|------|------|
| V <sub>CBO</sub> | collector-base voltage    | open emitter                          | -    | 20   | V    |
| V <sub>CEO</sub> | collector-emitter voltage | open base                             | -    | 10   | V    |
| V <sub>EBO</sub> | emitter-base voltage      | open collector                        | -    | 2.5  | V    |
| I <sub>C</sub>   | DC collector current      |                                       | -    | 50   | mA   |
| P <sub>tot</sub> | total power dissipation   | up to $T_s = 118 \text{ °C}$ ; note 1 | -    | 300  | mW   |
| T <sub>stg</sub> | storage temperature       |                                       | -65  | 150  | °C   |
| Tj               | junction temperature      |                                       | -    | 175  | °C   |

#### Note

1.  $T_s$  is the temperature at the soldering point of the collector tab.

**Product specification** 



### BFQ67W

#### THERMAL RESISTANCE

| SYMBOL              | PARAMETER   | CONDITIONS                                  | THERMAL RESISTANCE |
|---------------------|---|---|--------------------|
| R <sub>th j-s</sub> | thermal resistance from junction to soldering point | up to $T_s = 118 \ ^\circ\text{C}$ ; note 1 | 190 K/W            |

#### Note

1.  $\ensuremath{ T_s}$  is the temperature at the soldering point of the collector tab.

#### CHARACTERISTICS

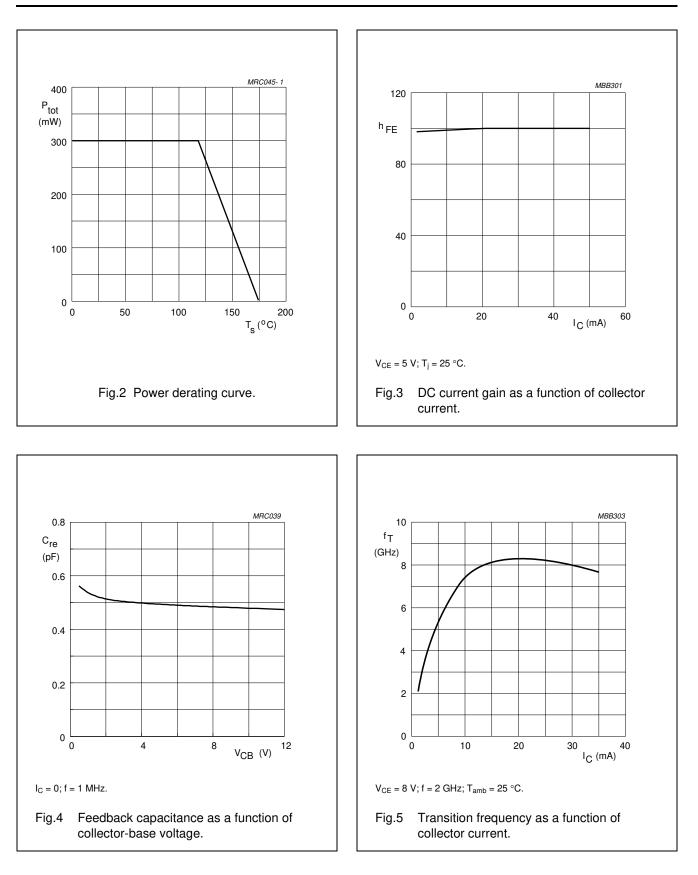
 $T_j$  = 25 °C, unless otherwise specified.

| SYMBOL           | PARAMETER                              | CONDITIONS   | MIN. | TYP. | MAX. | UNIT |
|------------------|--|--|------|------|------|------|
| I <sub>CBO</sub> | collector cut-off current              | $I_{E} = 0; V_{CB} = 5 V$  | -    | -    | 50   | nA   |
| h <sub>FE</sub>  | DC current gain                        | I <sub>C</sub> = 15 mA; V <sub>CE</sub> = 5 V  | 60   | 100  | -    |      |
| C <sub>c</sub>   | collector capacitance                  | $I_E = i_e = 0; V_{CB} = 8 V; f = 1 MHz$   | -    | 0.7  | _    | pF   |
| C <sub>e</sub>   | emitter capacitance                    | $I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$   | -    | 1.3  | -    | pF   |
| C <sub>re</sub>  | feedback capacitance                   | $I_{C} = 0; V_{CB} = 8 V; f = 1 MHz$   | _    | 0.5  | _    | pF   |
| f <sub>T</sub>   | transition frequency                   | $I_{C} = 15 \text{ mA}; V_{CE} = 8 \text{ V}; f = 2 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$  | -    | 8    | _    | GHz  |
| G <sub>UM</sub>  | maximum unilateral power gain (note 1) | $I_{C}$ = 15 mA; $V_{CE}$ = 8 V; f = 1 GHz<br>T <sub>amb</sub> = 25 °C   | -    | 13   | _    | dB   |
|                  |  | $\label{eq:lc} \begin{array}{l} I_C = 15 \text{ mA};  V_{CE} = 8  \text{V};  \text{f} = 2  \text{GHz}; \\ T_{amb} = 25 ^\circ\text{C} \end{array}$ | -    | 8    | -    | dB   |
| F                | noise figure                           | $\Gamma_{s} = \Gamma_{opt}$ ; I <sub>C</sub> = 5 mA; V <sub>CE</sub> = 8 V;<br>f = 1 GHz   | -    | 1.3  | _    | dB   |
|                  |  | $\Gamma_{s} = \Gamma_{opt}$ ; I <sub>C</sub> = 15 mA; V <sub>CE</sub> = 8 V;<br>f = 1 GHz  | -    | 2    | _    | dB   |
|                  |  | $\Gamma_{s} = \Gamma_{opt}$ ; I <sub>C</sub> = 5 mA; V <sub>CE</sub> = 8 V;<br>f = 2 GHz   | -    | 2.2  | _    | dB   |
|                  |  | $I_C$ = 5 mA; V <sub>CE</sub> = 8 V;<br>f = 2 GHz; Z <sub>s</sub> = 60 Ω   | -    | 2.5  | _    | dB   |
|                  |  | $\Gamma_{s} = \Gamma_{opt}$ ; I <sub>C</sub> = 15 mA; V <sub>CE</sub> = 8 V;<br>f = 2 GHz  | -    | 2.7  | _    | dB   |
|                  |  | $I_{C} = 5 \text{ mA}; V_{CE} = 8 \text{ V};$<br>f = 2 GHz; Z <sub>s</sub> = 60 $\Omega$   | -    | 3    | _    | dB   |

#### Note

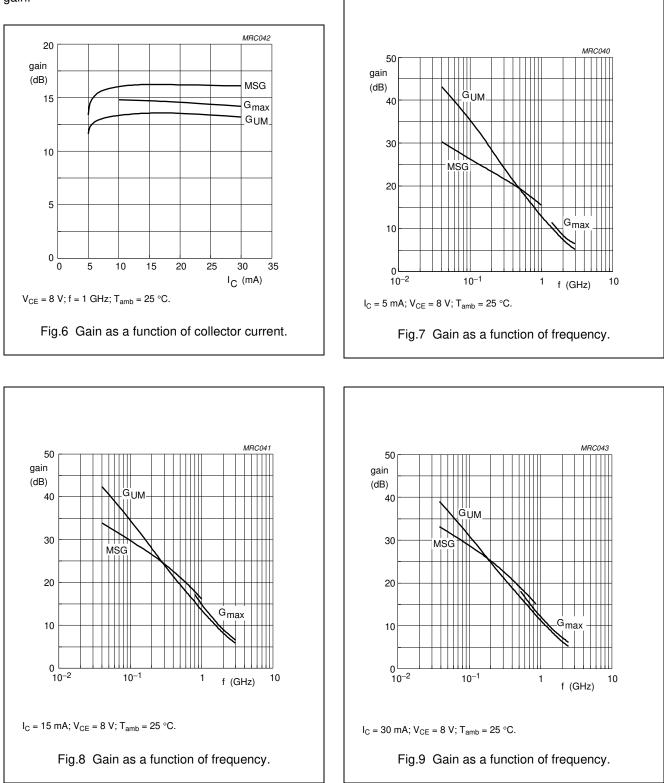
1.  $G_{UM}$  is the maximum unilateral power gain, assuming  $S_{12}$  is zero and

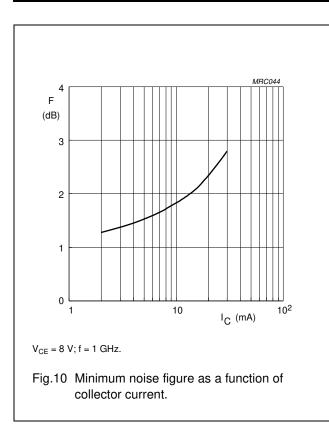
$$G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} dB.$$

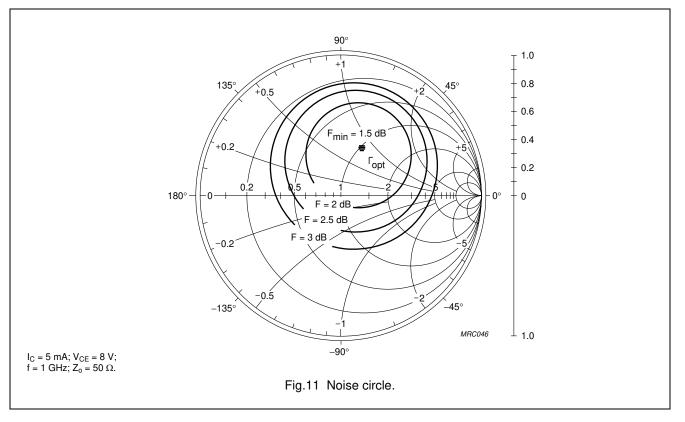


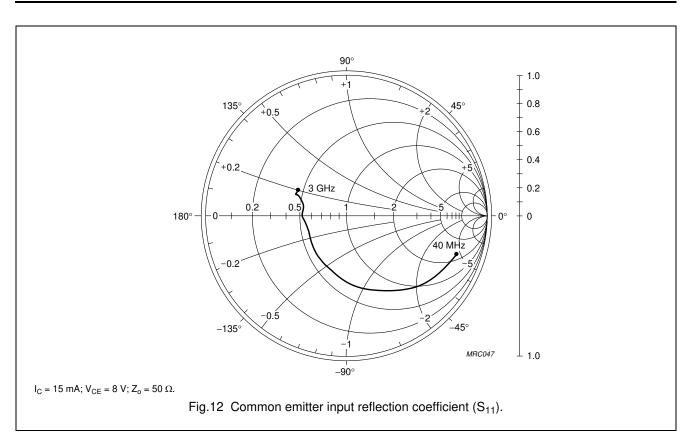
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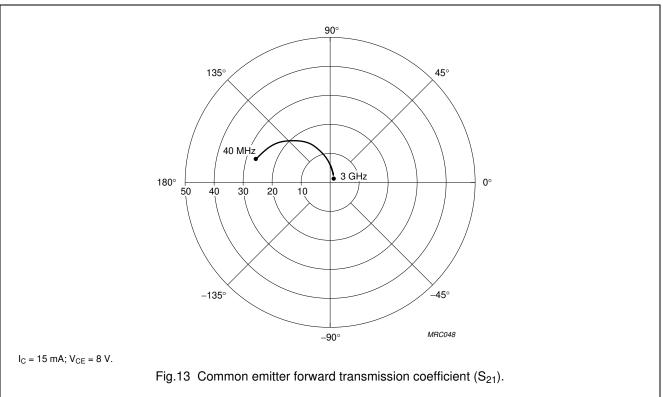
In Figs 6 to 9,  $G_{UM}$  = maximum unilateral power gain; MSG = maximum stable gain;  $G_{max}$  = maximum available gain.

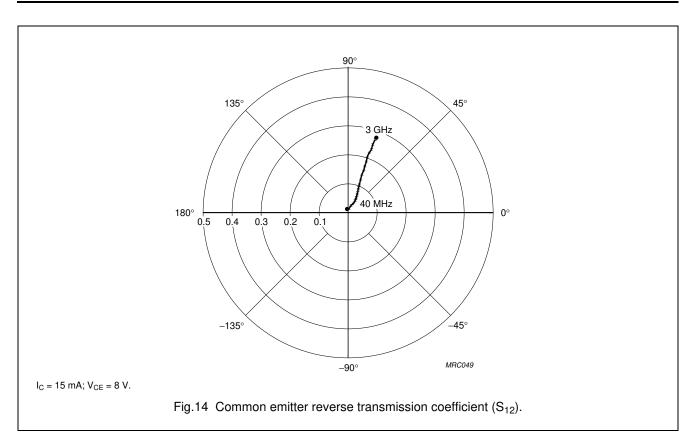


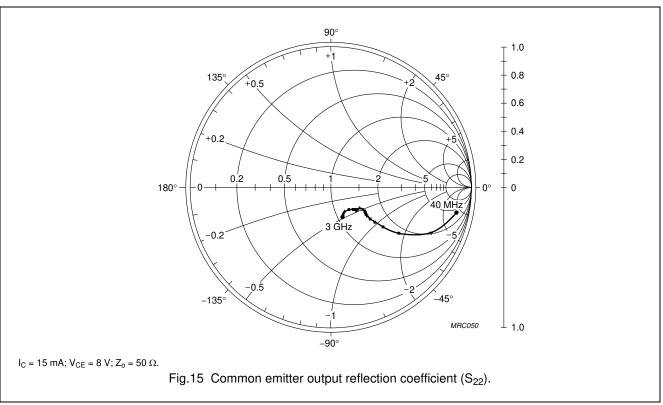








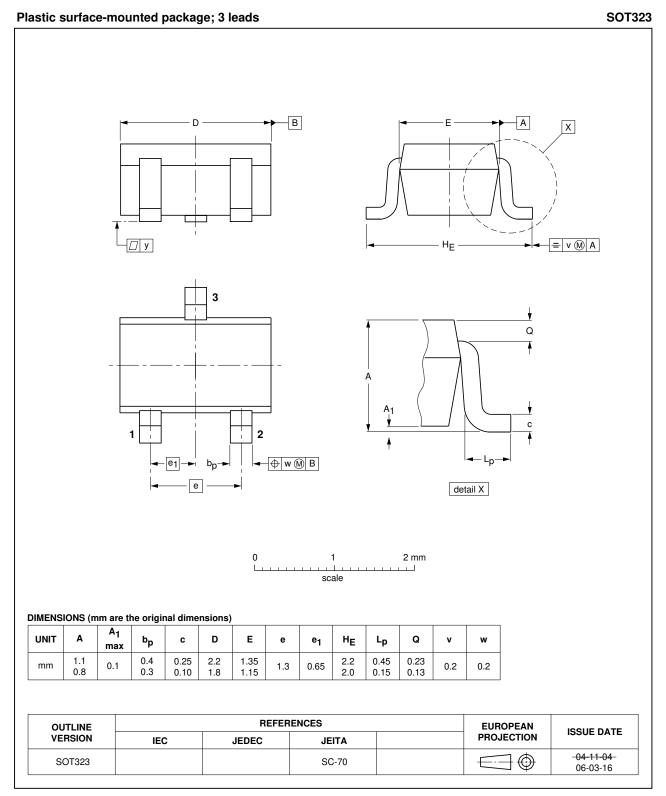




BFQ67W

### NPN 8 GHz wideband transistor

#### PACKAGE OUTLINE



BFQ67W

#### DATA SHEET STATUS

| DOCUMENT<br>STATUS <sup>(1)</sup> | PRODUCT<br>STATUS <sup>(2)</sup> | DEFINITION  |
|-----------------------------------|----------------------------------|---|
| Objective data sheet              | Development                      | This document contains data from the objective specification for product development. |
| Preliminary data sheet            | Qualification                    | This document contains data from the preliminary specification.                       |
| Product data sheet                | Production                       | This document contains the product specification.                                     |

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#### **Contact information**

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